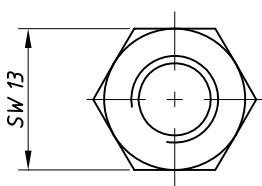
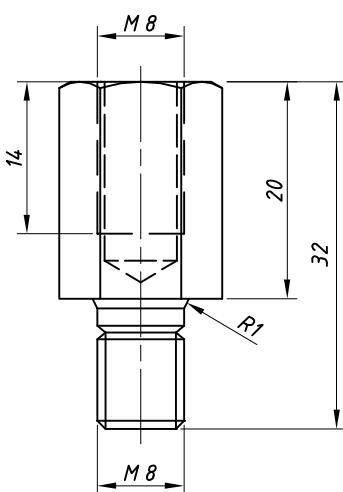
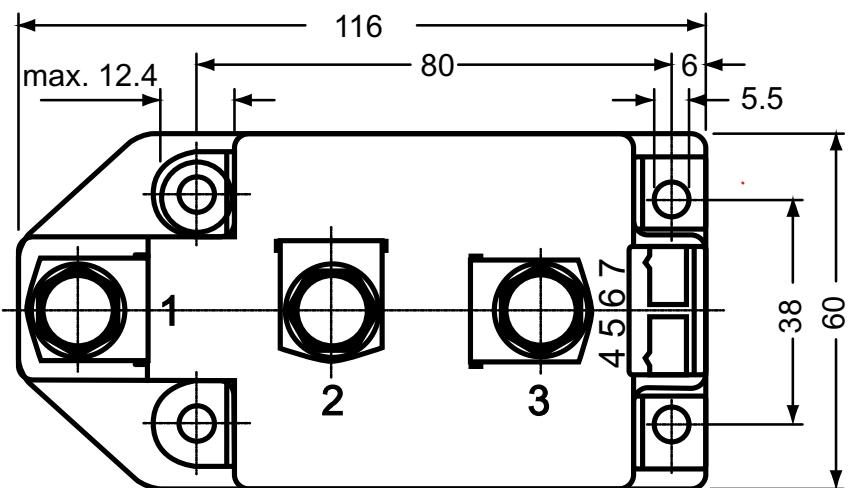
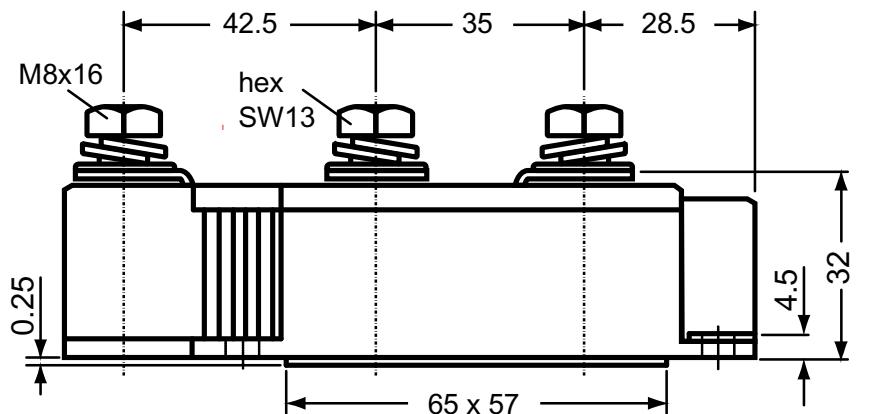


Dimensions in mm (1 mm = 0.0394")



Threaded spacer for higher Anode /
Cathode construction:

Type **ZY 250** (material brass)

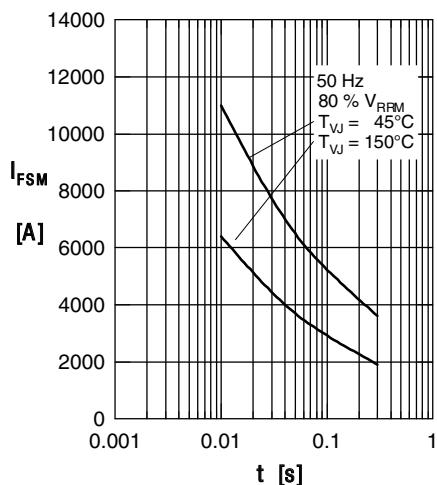


Fig. 1 Surge overload current
 $I_{F\text{SM}}$: Crest value, t : duration

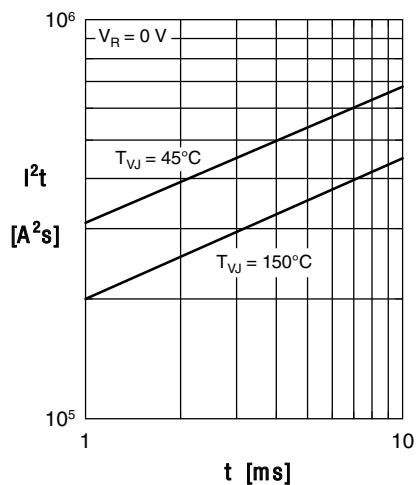


Fig. 2 I^2t versus time (1-10 ms)

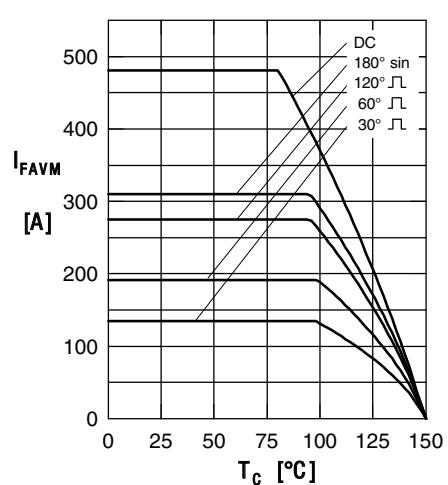


Fig. 3 Maximum forward current
at case temperature

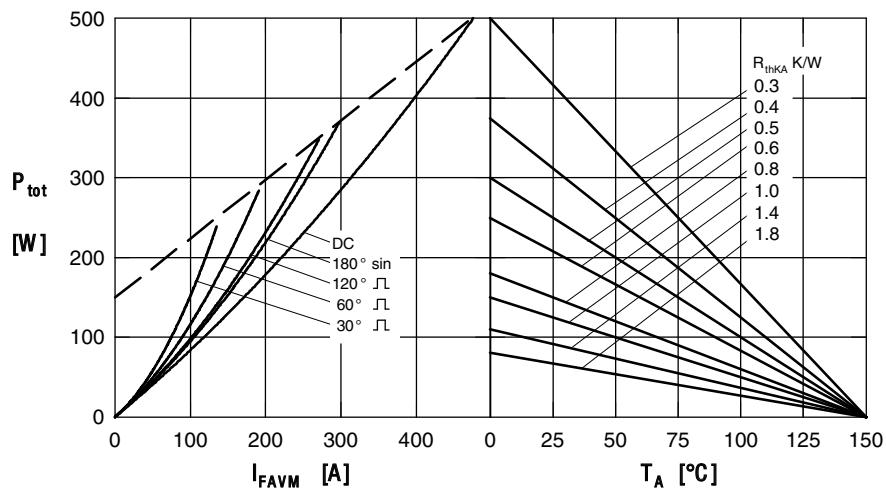


Fig. 4 Power dissipation versus forward current
and ambient temperature (per diode)

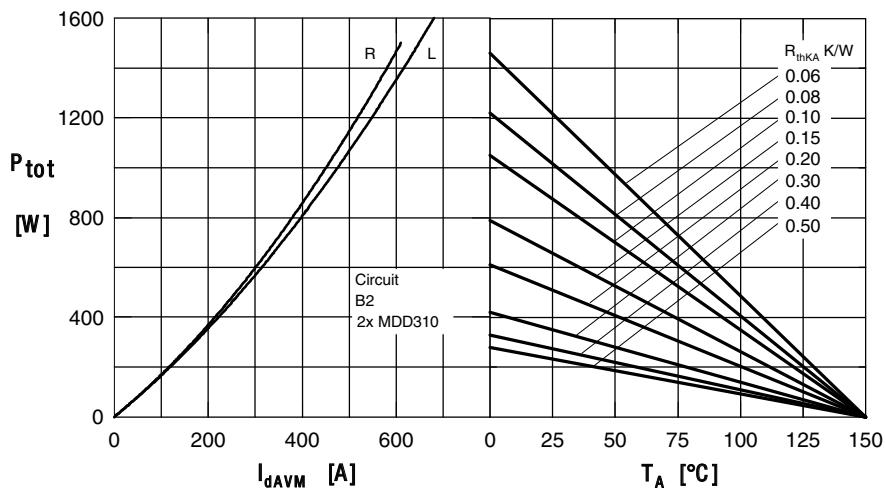


Fig. 5 Single phase rectifier bridge: Power dissipation vs. direct output current
and ambient temperature R = resistive load, L = inductive load

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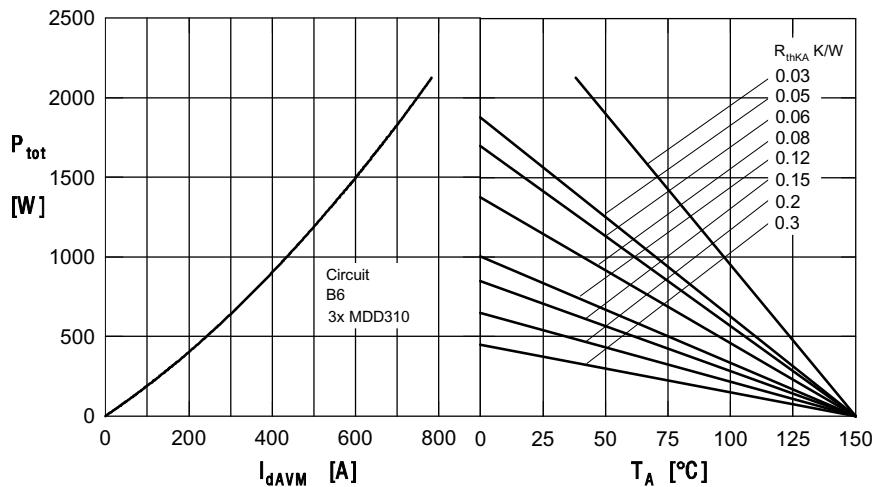


Fig.6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

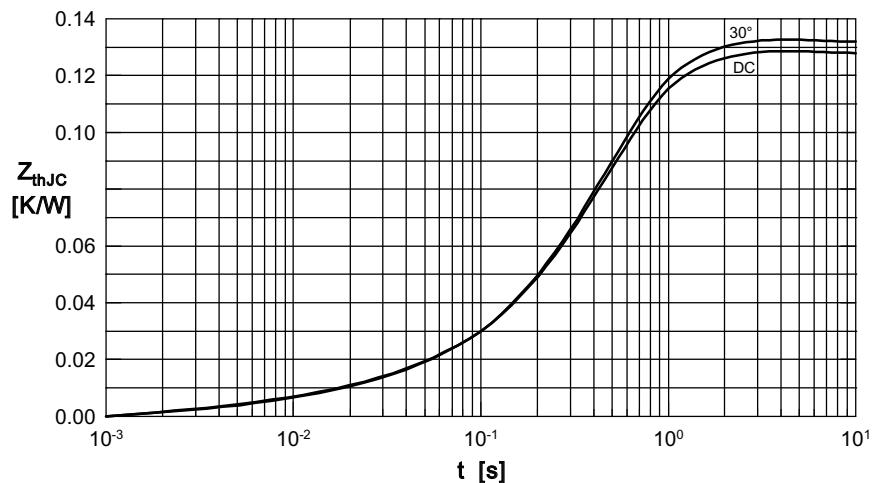


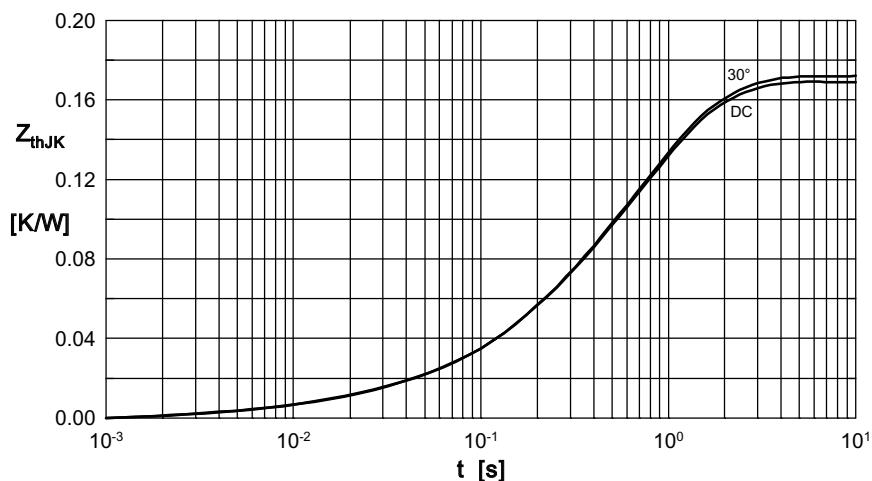
Fig. 7 Transient thermal impedance junction to case (per diode)

R_{thJC} for various conduction angles d:

| d | R _{thJC} [K/W] |
|------|-------------------------|
| DC | 0.129 |
| 180° | 0.131 |
| 120° | 0.132 |
| 60° | 0.132 |
| 30° | 0.133 |

Constants for Z_{thJC} calculation:

| i | R _{thi} [K/W] | t _i [s] |
|---|------------------------|--------------------|
| 1 | 0.0035 | 0.0099 |
| 2 | 0.0165 | 0.168 |
| 3 | 0.1091 | 0.456 |



R_{thJK} for various conduction angles d:

| d | R _{thJK} (K/W) |
|------|-------------------------|
| DC | 0.169 |
| 180° | 0.171 |
| 120° | 0.172 |
| 60° | 0.172 |
| 30° | 0.173 |

Constants for Z_{thJK} calculation:

| i | R _{thi} (K/W) | t _i (s) |
|---|------------------------|--------------------|
| 1 | 0.0035 | 0.0099 |
| 2 | 0.0165 | 0.168 |
| 3 | 0.1091 | 0.456 |
| 4 | 0.04 | 1.36 |

Fig. 8 Transient thermal impedance junction to heatsink (per diode)

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